INTEGRATED CIRCUITS



Product specification IC24 Data Handbook 1997 Jun 30



Philips Semiconductors

74LVC08A

FEATURES

- Wide supply voltage range of 1.2 V to 3.6 V
- In accordance with JEDEC standard no. 8-1A
- Inputs accept voltages up to 5.5 V
- CMOS low power consumption
- Direct interface with TTL levels

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5$ ns

DESCRIPTION

The 74LVC08A is a high-performance, low-power, low-voltage, Si-gate CMOS device and superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in a mixed 3.3 V/5 V environment.

The 74LVC08A provides the 2-input AND function.

SYMBOL	PARAMETER CONDITIONS		TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay nA, nB to nY	C _L = 50 pF; V _{CC} = 3.3 V	2.6	ns
Cl	Input capacitance		5.0	pF
C _{PD}	Power dissipation capacitance per gate	Notes 1 and 2	28	pF

NOTES:

1. C_{PD} is used to determine the dynamic power dissipation $(P_D \text{ in } \mu W)$

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz; C_L = output load capacity in pF; f_o = output frequency in MHz; V_{CC} = supply voltage in V;

- $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of the outputs.}$
- 2. The condition is $V_1 = GND$ to V_{CC} .

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic SO	–40°C to +85°C	74LVC08A D	74LVC08A D	SOT108-1
14-Pin Plastic SSOP Type II	–40°C to +85°C	74LVC08A DB	74LVC08A DB	SOT337-1
14-Pin Plastic TSSOP Type I	–40°C to +85°C	74LVC08A PW	74LVC08APW DH	SOT402-1

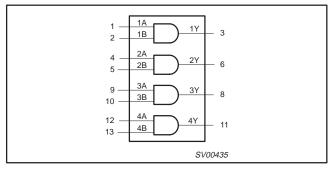
PIN CONFIGURATION

1A 1	14	V _{CC}
1B 2	13	4B
1Y 3	12	4A
2A 4	11	4Y
2B 5	10	3B
2Y 6	9	3A
GND 7	8	3Y
	SY00034	

PIN DESCRIPTION

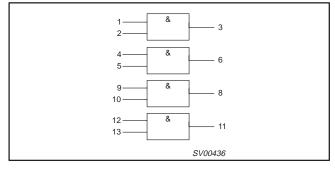
PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 4, 9, 12	1A – 4A	Data inputa
2, 5, 10, 13	1B – 4B	Data inputs
3, 6, 8, 11	1Y – 4Y	Data outputs
7	GND	Ground (0 V)
14	V _{CC}	Positive supply voltage

LOGIC SYMBOL

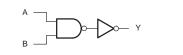


74LVC08A

LOGIC SYMBOL (IEEE/IEC)



LOGIC DIAGRAM (ONE GATE)



SV00415

FUNCTION TABLE

INP	OUTPUTS	
nA	nB	nY
L	L	L
L	Н	L
Н	L	L
Н	Н	Н

NOTES:

H = HIGH voltage level L = LOW voltage level

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LIM	UNIT	
STWDUL		CONDITIONS	MIN	MAX	
V _{CC}	DC supply voltage (for max. speed performance)		2.7	3.6	V
V _{CC}	DC supply voltage (for low-voltage applications)		1.2	3.6	V
VI	DC input voltage range		0	5.5	V
V _O	DC output voltage range; output HIGH or LOW state		0	V _{CC}	V
T _{amb}	Operating ambient temperature range in free-air		-40	+85	°C
t _r , t _f	Input rise and fall times	V _{CC} = 1.2 to 2.7V V _{CC} = 2.7 to 3.6V	0 0	20 10	ns/V

ABSOLUTE MAXIMUM RATINGS¹

In accordance with the Absolute Maximum Rating System (IEC 134). Voltages are referenced to GND (ground = 0V).

SYMBOL	PARAMETER	PARAMETER CONDITIONS		UNIT
V _{CC}	DC supply voltage		-0.5 to +6.5	V
I _{IK}	DC input diode current	$V_{I} < 0$	-50	mA
VI	DC input voltage	Note 2	-0.5 to +6.5	V
I _{OK}	DC output diode current	$V_{O} > V_{CC}$ or $V_{O} < 0$	± 50	mA
Vo	DC output voltage; output HIGH or LOW state	Note 2	–0.5 to V _{CC} +0.5	V
Ι _Ο	DC output source or sink current	k current $V_{O} = 0$ to V_{CC}		mA
I _{GND} , I _{CC}	DC V _{CC} or GND current		±100	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{TOT}	Power dissipation per package – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	500 500	mW

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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DC CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V).

			L	LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = -				
			MIN	TYP ¹	MAX	1	
V		V _{CC} = 1.2V	V _{CC}			V	
VIH	HIGH level Input voltage	V _{CC} = 2.7 to 3.6V	2.0			1 [×]	
M		V _{CC} = 1.2V			GND	V	
VIL	V _{IL} LOW level Input voltage	V _{CC} = 2.7 to 3.6V			0.8	1 [×]	
		$V_{CC} = 2.7V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -12mA$	V _{CC} -0.5				
M		$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -100\mu A$	V _{CC} -0.2	V _{CC}		1	
V _{OH}	HIGH level output voltage	$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -18mA$	V _{CC} -0.6				
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -24mA$	V _{CC} -0.8			1	
		$V_{CC} = 2.7V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 12mA$			0.40		
V _{OL}	LOW level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$			0.20	V	
		$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 24mA$			0.55	1	
t _l	Input leakage current	$V_{CC} = 3.6V; V_{I} = 5.5V \text{ or GND}$		±0.1	±5	μA	
I _{CC}	Quiescent supply current	$V_{CC} = 3.6V; V_I = V_{CC} \text{ or GND}; I_O = 0$		0.1	10	μΑ	
ΔI_{CC}	Additional quiescent supply current per input pin	V_{CC} = 2.7V to 3.6V; $V_{\rm I}$ = V_{CC} –0.6V; I_{O} = 0		5	500	μA	

NOTE:

1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

AC CHARACTERISTICS

GND = 0 V; t_r = $t_f\,\leq\,$ 2.5 ns; C_L = 50 pF

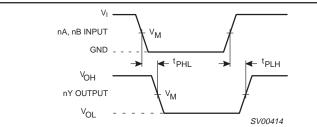
			LIMITS							
SYMBOL	PARAMETER	WAVEFORM	V _{CC}	= 3.3V ±0).3V	١	/ _{CC} = 2.7\	/	V _{CC} = 1.2V	UNIT
			MIN	TYP ¹	MAX	MIN	TYP	MAX	TYP	
t _{PHL} / t _{PLH}	Propagation delay nA, nB to nY	1, 2	1.5	2.6	5.1	1.5	3.0	6.1	16	ns

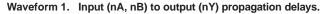
NOTE:

1. These typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

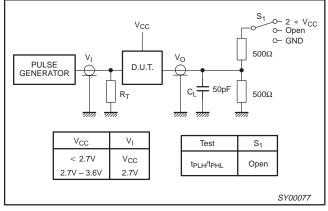
AC WAVEFORMS

 $V_{\mbox{OL}}$ and $V_{\mbox{OH}}$ are the typical output voltage drop that occur with the output load.



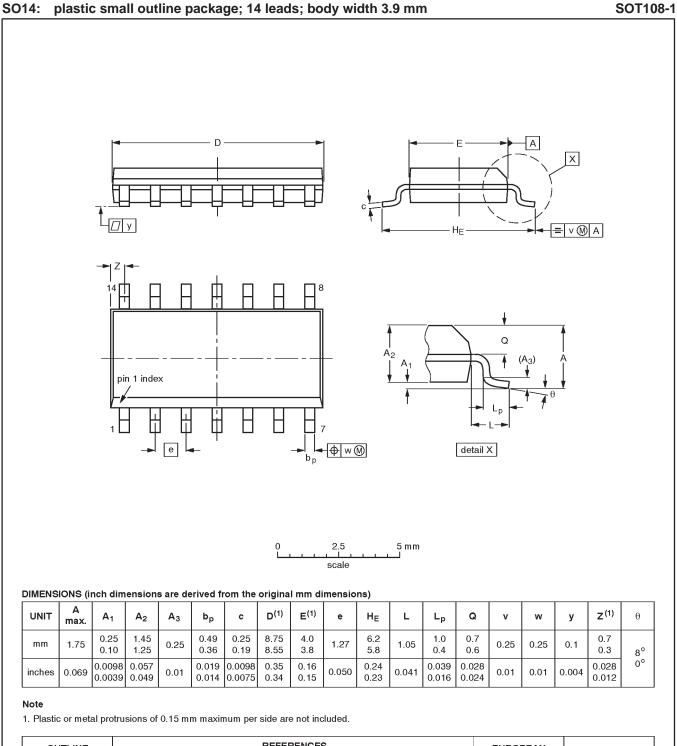


TEST CIRCUIT



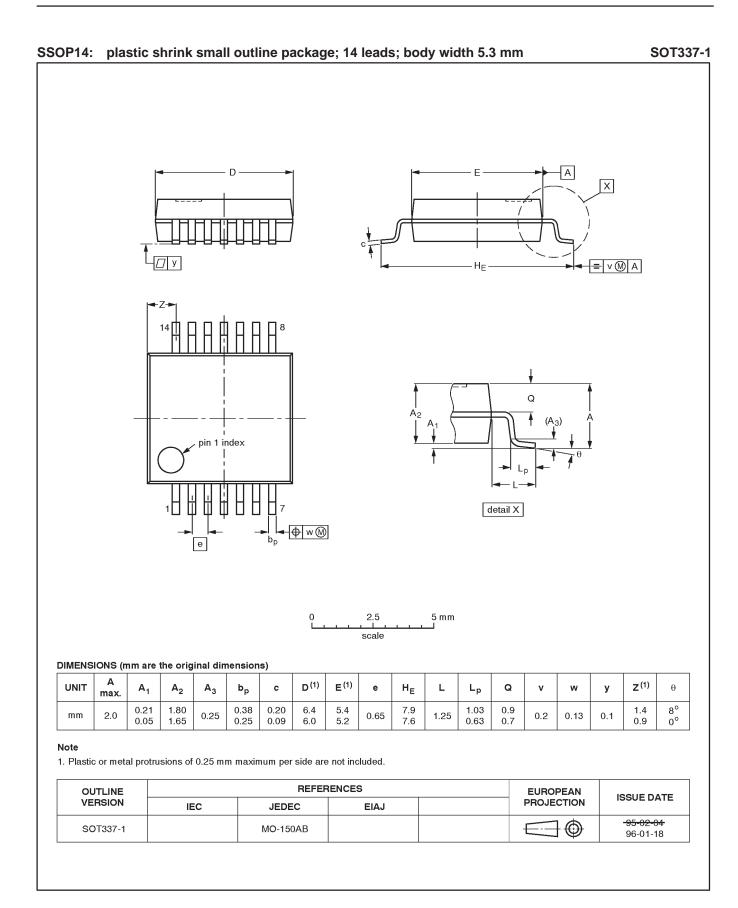
Waveform 2. Load circuitry for switching times.

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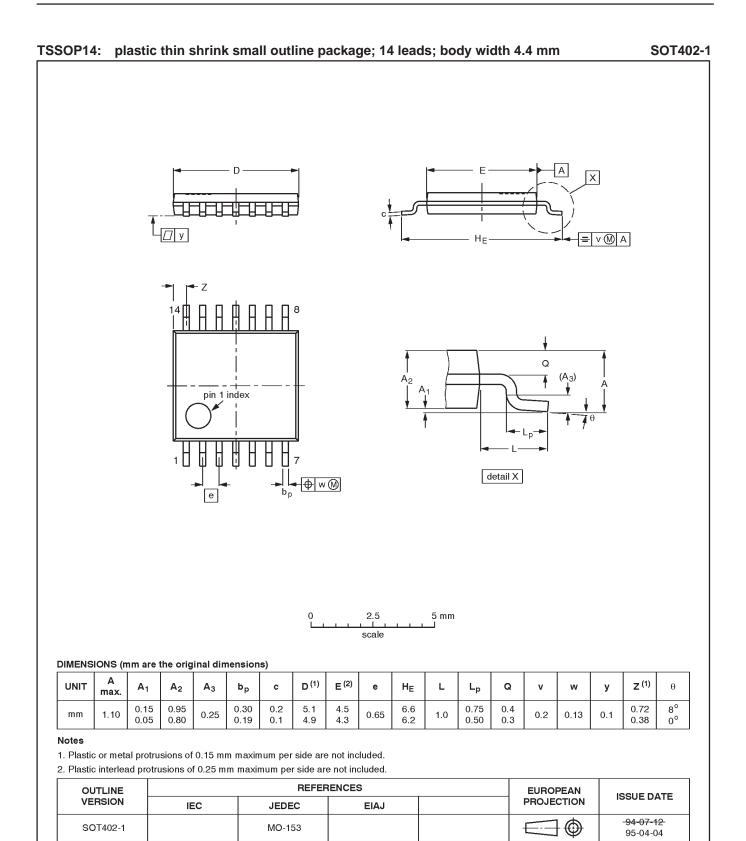


OUTLINE		REFEF	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT108-1	076E06\$	MS-012AB				91-08-13 95-01-23

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